

Confirmation No.6431

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	PONOMAREV	Examiner:	Whalen, D.
Serial No.:	10/596,422	Group Art Unit:	4176
Filed:	June 13, 2006	Docket No.:	NL03 1497 US1
Title:	METHOD FOR FORMING A STRAINED SI-CHANNEL IN A MOSFET STRUCTURE		

AMENDMENT AND RESPONSE

Mail Stop Amendment AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Customer No. 65913

Dear Sir:

In response to the final Office Action dated April 10, 2008, please reconsider the application in view of the following amendments and remarks.

A complete listing of the claims, to include any amendments presented therein, begins on page 2 of this paper.

Remarks/Arguments follow on page 4.

Authorization is provided to charge/credit Deposit Account 50-4019 any requisite fees/overages to enter this paper.